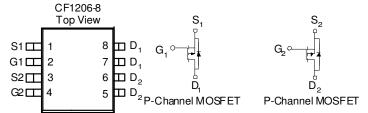
P-Channel 30-V (D-S) MOSFET

These miniature surface mount MOSFETs utilize a high cell density trench process to provide low $r_{DS(on)}$ and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

| | 1 | |
|---|---|--|
| • | | Low r _{DS(on)} provides higher efficiency and |
| | | extends battery life |

- Low thermal impedance copper leadframe CF1206-8 saves board space
- Fast switching speed
- High performance trench technology

| PRODUCT SUMMARY | | | | | | |
|---|--------------------------|------|--|--|--|--|
| $oxed{V_{DS}(V) \qquad r_{DS(on)}(OHM) \qquad I_D}$ | | | | | | |
| -30 | $0.084 @ V_{GS} = -10V$ | -3.1 | | | | |
| -30 | $0.130 @ V_{GS} = -4.5V$ | -2.5 | | | | |



| ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C UNLESS OTHERWISE NOTED) | | | | | | |
|--|-------------------------------------|------------|-------|---|--|--|
| Parameter | Symbol | Maximum | Units | | | |
| Drain-Source Voltage | V_{DS} | -30 | V | | | |
| Gate-Source Voltage | V_{GS} | ±20 | v | | | |
| Continuous Drain Current ^a | $T_A=25^{\circ}C$ | | -3.1 | | | |
| Continuous Drain Current | $T_A=25^{\circ}C$ $T_A=70^{\circ}C$ | П | -2.5 | A | | |
| Pulsed Drain Current ^b | I_{DM} | -10 | | | | |
| Continuous Source Current (Diode Conduction) ^a | | I_S | ±1.6 | A | | |
| D D: a | $T_A=25^{\circ}C$ | D | 1.15 | W | | |
| Power Dissipation ^a | $T_A=25^{\circ}C$ $T_A=70^{\circ}C$ | PD | 0.7 | | | |
| Operating Junction and Storage Temperature Range | T _J , T _{stg} | -55 to 150 | °C | | | |

| THERMAL RESISTANCE RATINGS | | | | | | | |
|--|--------------|--------------------|-----|-----|------|--|--|
| Parameter | Symbol | Тур | Max | | | | |
| Mariana Indiana Analizada | t <= 10 sec | R_{thJA} | 93 | 110 | °C/W | | |
| Maximum Junction-to-Ambient ^a | Steady State | T _{th} JA | 130 | 150 | | | |

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Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

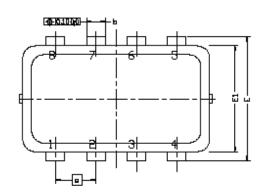
| SPECIFICATIONS (T _A = 25°C UNLESS OTHERWISE NOTED) | | | | | | | | |
|---|---------------------|---|--------|-------|-------|----------|--|--|
| Danamatan | Cymbol | T4 C 114 | Limits | | | T 1:4 | | |
| Parameter | Symbol | Test Conditions | Min | Тур | Max | Unit | | |
| Static | | | | | | | | |
| Gate-Threshold Voltage | $V_{GS(th)}$ | $V_{DS} = V_{GS}, I_{D} = -250 \text{ uA}$ | -1.00 | | | | | |
| Gate-Body Leakage | I_{GSS} | $V_{DS} = 0 \text{ V}, V_{GS} = +/-20 \text{ V}$ | | | ±100 | nA | | |
| Zero Gate Voltage Drain Current | I _{DSS} | $V_{DS} = -24 \text{ V}, V_{GS} = 0 \text{ V}$ | | -1 | | uA | | |
| Zero Gate Voltage Drain Current | DSS | $V_{DS} = -24 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$ | | | -10 | | | |
| On-State Drain Current ^A | $I_{D(on)}$ | $V_{DS} = -5 \text{ V}, V_{GS} = -10 \text{ V}$ | -3 | | | A | | |
| Drain-Source On-Resistance ^A | r | $V_{GS} = -10 \text{ V}, I_D = -2.5 \text{ A}$ | 5 A | | 0.084 | Ω | | |
| Drain-Source On-Resistance | r _{DS(on)} | $V_{GS} = -4.5 \text{ V}, I_D = -1.2 \text{ A}$ | | | 0.130 | 32 | | |
| Forward Tranconductance ^A | ${f g}_{ m fs}$ | $V_{DS} = -5 \text{ V}, I_{D} = -2.5 \text{ A}$ | | 3 | | S | | |
| Diode Forward Voltage | V_{SD} | $I_S = -1.6 \text{ A}, V_{GS} = 0 \text{ V}$ | | -0.70 | | V | | |
| Dynamic ^b | - | | • | | | <u>-</u> | | |
| Total Gate Charge | Q_{g} | V - 5 V V - 45 V | | 6.0 | | | | |
| Gate-Source Charge | Q_{gs} | $V_{DS} = -5 \text{ V}, V_{GS} = -4.5 \text{ V},$ $I_{D} = -2.5 \text{ A}$ | | 0.80 | | nC | | |
| Gate-Drain Charge | Q_{gd} | $I_D = -2.3 A$ | | 1.30 | | | | |
| Turn-On Delay Time | $t_{d(on)}$ | and desired to | | 6.5 | | | | |
| Rise Time | $t_{\rm r}$ | $V_{DD} = -5 \text{ V}, R_L = 5 \text{ OHM},$ | | 20 | | ns | | |
| Turn-Off Delay Time | $t_{ m d(off)}$ | $V_{GEN} = -4.5 \text{ V}, R_G = 6 \text{ OHM}$ | | 31 | | | | |
| Fall-Time | t_{f} | | | 21 | | | | |

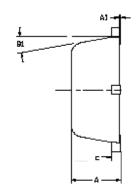
Notes

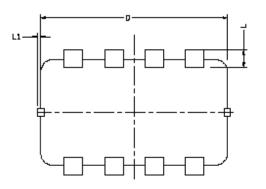
- a. Pulse test: $PW \le 300$ us duty cycle $\le 2\%$.
- b. Guaranteed by design, not subject to production testing.

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Package Information







| DIM. | MILLIMETERS | | INCHES | | | |
|----------|----------------------|--------|--------|--------|--------|--------|
| יוגונית | MEN | | MAX | MIN | NOM | MAX |
| Α | Q700 | 0.80 | מספגם | 0.0276 | 0.0315 | 0.0334 |
| Al | 딦 | - | 0,05 | 0.000 | - | 0.002 |
| b | 0.24 | 0.30 | 1.35 | 0.009 | 0.012 | 0.014 |
| С | 91.0 | 0.152 | 1.25 | 0013 | 0,006 | 0,010 |
| D | 3.00 BSC 0.118 BS | | | | | C |
| Ε | Ē | OD B5 | Ç | Ů, | 079 B: | 汇 |
| El | 1.70 BSC 0.067 BSC | | | | | XC |
| 6 | ¢ | .65 BS | Ç | Ü | 026 B: | ;C |
| L | ¢.20 | 0.275 | 0.400 | 0,000 | 0.011 | 0.0157 |
| Li | Ď | | 0.108 | Ö | | 0.004 |
| 1 | Ü, | 10 | 12* | 0' | 10° | 12* |